

# ESD249-B1-W0201

## Protection Devices

TVS (Transient Voltage Suppressor)

Bi-directional, 18 V, 4.2 pF, 0201, RoHS and Halogen Free compliant

## Features

- ESD / transient protection according to:
  - IEC61000-4-2 (ESD):  $\pm 16$  kV (air / (contact discharge)
  - IEC61000-4-4 (EFT):  $\pm 2.5$  kV /  $\pm 50$  A (5/50 ns)
  - IEC61000-4-5 (Surge):  $\pm 3$  A (8/20  $\mu$ s)
- Bi-directional working voltage up to:  $V_{RWM} = \pm 18$  V
- Line capacitance:  $C_L = 4.2$  pF (typical) at  $f = 1$  MHz
- Clamping voltage:  $V_{CL} = 23.5$  V (typical) at  $I_{TLP} = 16$  A with  $R_{DYN} = 0.27 \Omega$  (typical)
- Very low reverse current:  $I_R < 1$  nA (typical)
- Small form factor SMD Size 0201 and low profile 0.58 mm x 0.28 mm x 0.15 mm
- Bi-directional symmetric I/V characteristic for optimized design / assembly
- Pb-free (RoHS compliant) and halogen free package



Guidelines for optimized PCB design and assembly process are available in [\[2\]](#).

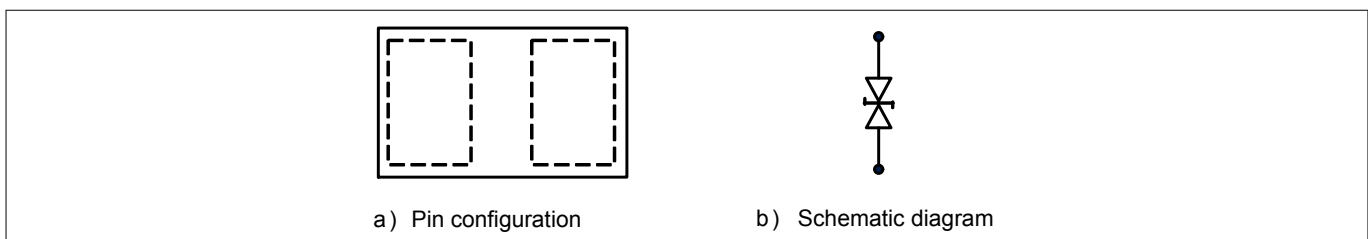
## Application examples

- ESD protection of highly susceptible IC / ASICs in audio, headset, and human digital interfaces
- Dedicated solution to boost space saving and high performance in miniaturized modern electronics

## Product validation

Qualified for industrial applications according to relevant tests of JEDEC 47/20/22

## Device information



**Figure 1** Pin configuration and schematic diagram

**Table 1** Part information

Type	Package	Configuration	Marking code
ESD249-B1-W0201	WLL-2-3	1 line, bi-directional	CC <sup>1)</sup>

<sup>1</sup> The device does not have any marking on the device top. The marking code is on pad side.

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Maximum ratings

## 1 Maximum ratings

Note:  $T_A = 25\text{ °C}$ , unless otherwise specified

Table 2 Maximum ratings<sup>1)</sup>

Parameter	Symbol	Values	Unit
Reverse working voltage	$V_{RWM}$	$\pm 18$	V
ESD discharge <sup>2)</sup>	$V_{ESD}$ (contact)	$\pm 16$	kV
	$V_{ESD}$ (air)	$\pm 16$	
Peak pulse power <sup>3)</sup>	$P_{PK}$	72	W
Peak pulse current <sup>3)</sup>	$I_{PP}$	3	A
Operating temperature range	$T_{OP}$	-55 to 125	°C
Storage temperature	$T_{stg}$	-65 to 150	°C

**Attention:** Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.

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<sup>1</sup> Device is electrically symmetrical

<sup>2</sup>  $V_{ESD}$  according to IEC61000-4-2 (R = 330  $\Omega$ , C = 150 pF discharge network)

<sup>3</sup> Stress pulse: 8/20 $\mu$ s current waveform according to IEC61000-4-5

Electrical characteristics

2 Electrical characteristics

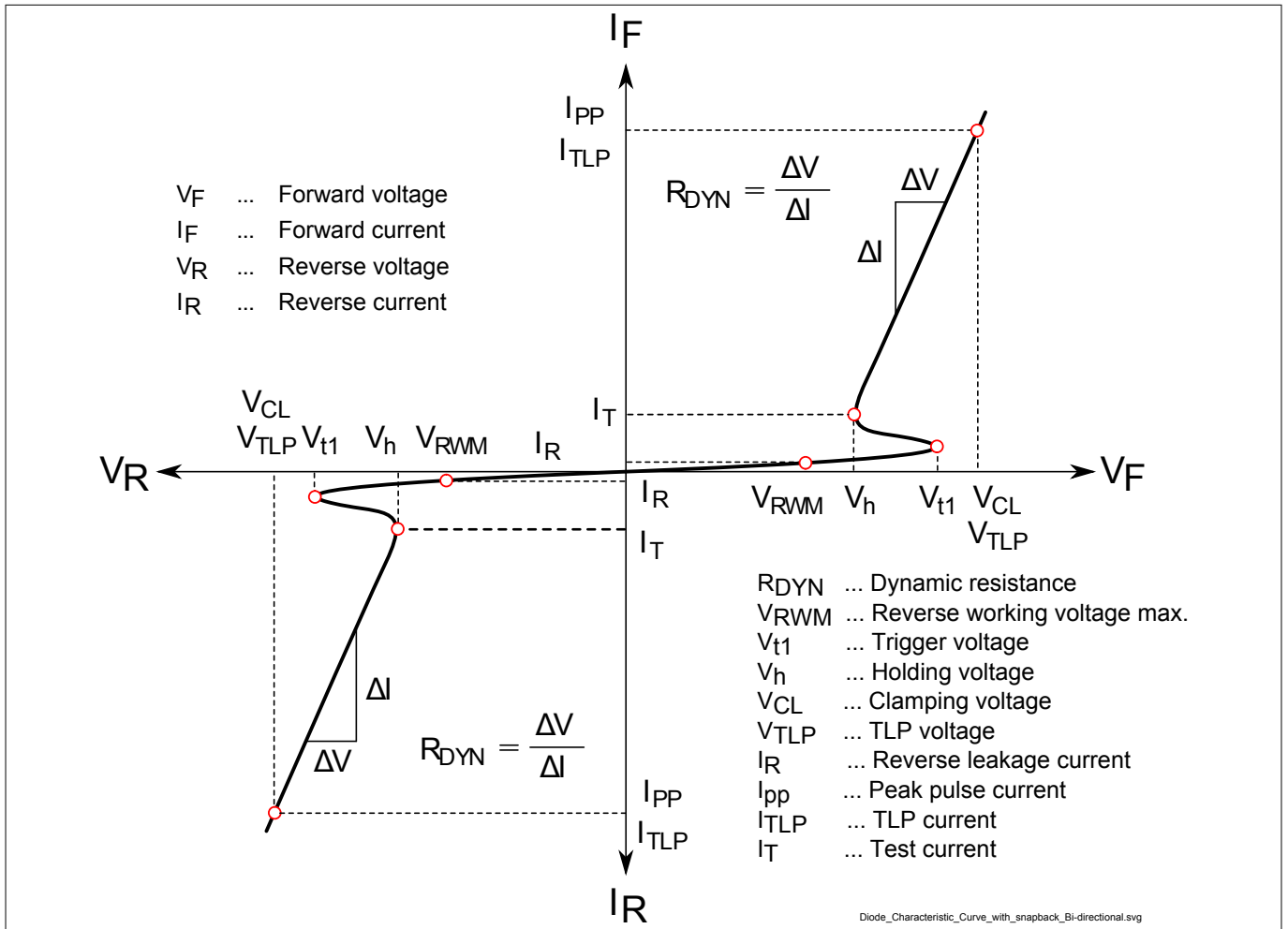


Figure 2 Definitions of electrical characteristics

**Electrical characteristics**

**Table 3 DC characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified) <sup>1)</sup>**

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Trigger voltage <sup>2) 3)</sup>	$V_{t1}$	20	23	26	V	–
Holding voltage <sup>4)</sup>	$V_h$	20	22.5	25.5	V	$I_T = 1\text{ mA}$
Reverse current	$I_R$	–	<1	100	nA	$V_R = 18\text{ V}$

**Table 4 AC characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified) <sup>1)</sup>**

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Line capacitance	$C_L$	–	4.2	6	pF	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$
		–	4.2	–		$V_R = 0\text{ V}$ , $f = 1\text{ GHz}$

**Table 5 ESD and Surge characteristics ( $T_A = 25\text{ °C}$ , unless otherwise specified) <sup>1)</sup>**

Parameter	Symbol	Values			Unit	Note or Test Condition
		Min.	Typ.	Max.		
Clamping voltage <sup>5)</sup>	$V_{CL}$	–	23.5	27	V	$I_{TLP} = 16\text{ A}$ , $t_p = 100\text{ ns}$
		–	27	–		$I_{TLP} = 30\text{ A}$ , $t_p = 100\text{ ns}$
Clamping voltage <sup>6)</sup>		–	21	–		$I_{PP} = 1\text{ A}$ , $t_p = 8/20\text{ }\mu\text{s}$
		–	23	–		$I_{PP} = 3\text{ A}$ , $t_p = 8/20\text{ }\mu\text{s}$
Dynamic resistance <sup>5)</sup>	$R_{DYN}$	–	0.27		$\Omega$	$t_p = 100\text{ ns}$

<sup>1)</sup> Device is electrically symmetrical

<sup>2)</sup> Verified by design

<sup>3)</sup> Voltage forced

<sup>4)</sup> Current forced

<sup>5)</sup> Please refer to Application Note AN210 [1]. TLP parameters:  $Z_0 = 50\text{ }\Omega$ ,  $t_p = 100\text{ ns}$ ,  $t_r = 0.6\text{ ns}$ .

<sup>6)</sup> Stress pulse: 8/20 $\mu\text{s}$  current waveform according to IEC61000-4-5

Typical characteristic diagrams

### 3 Typical characteristic diagrams

Note:  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise specified

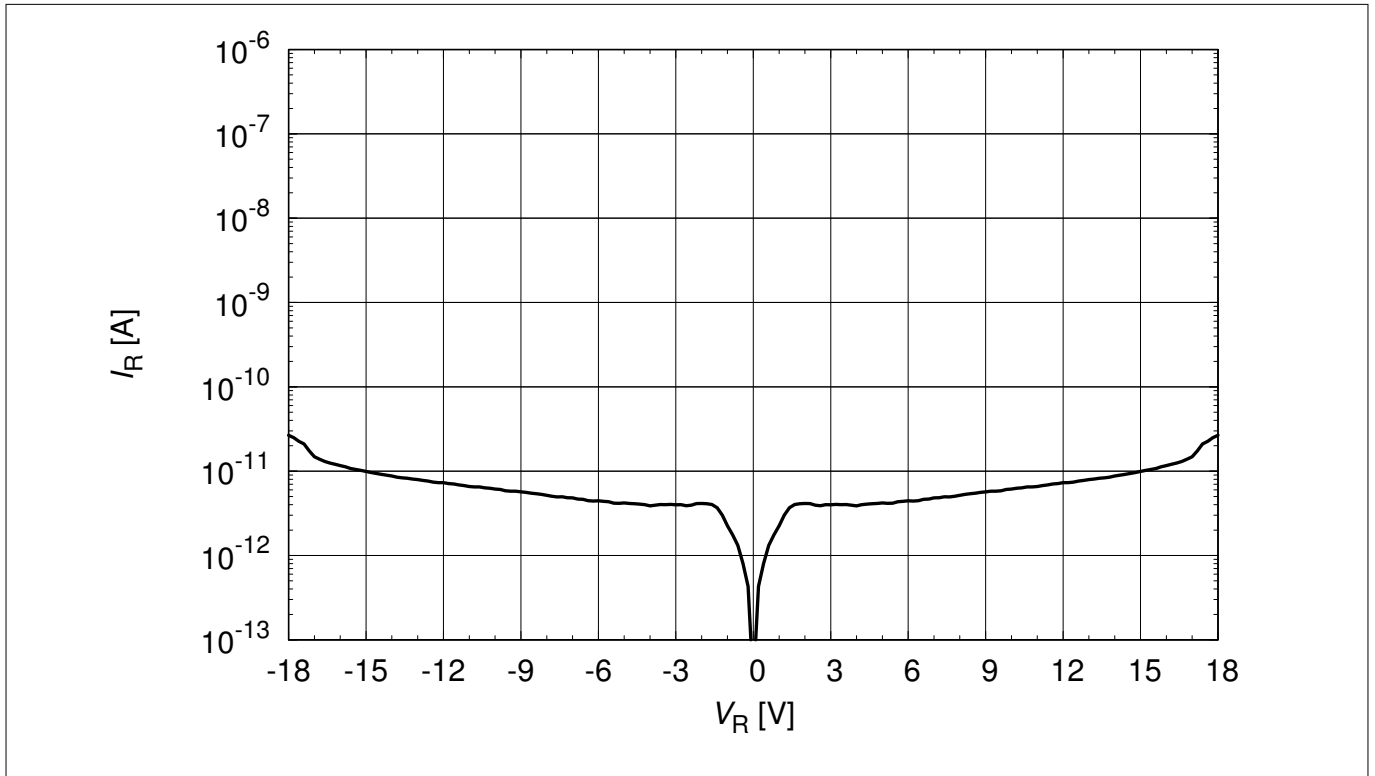


Figure 3 Reverse leakage current:  $I_R = f(V_R)$

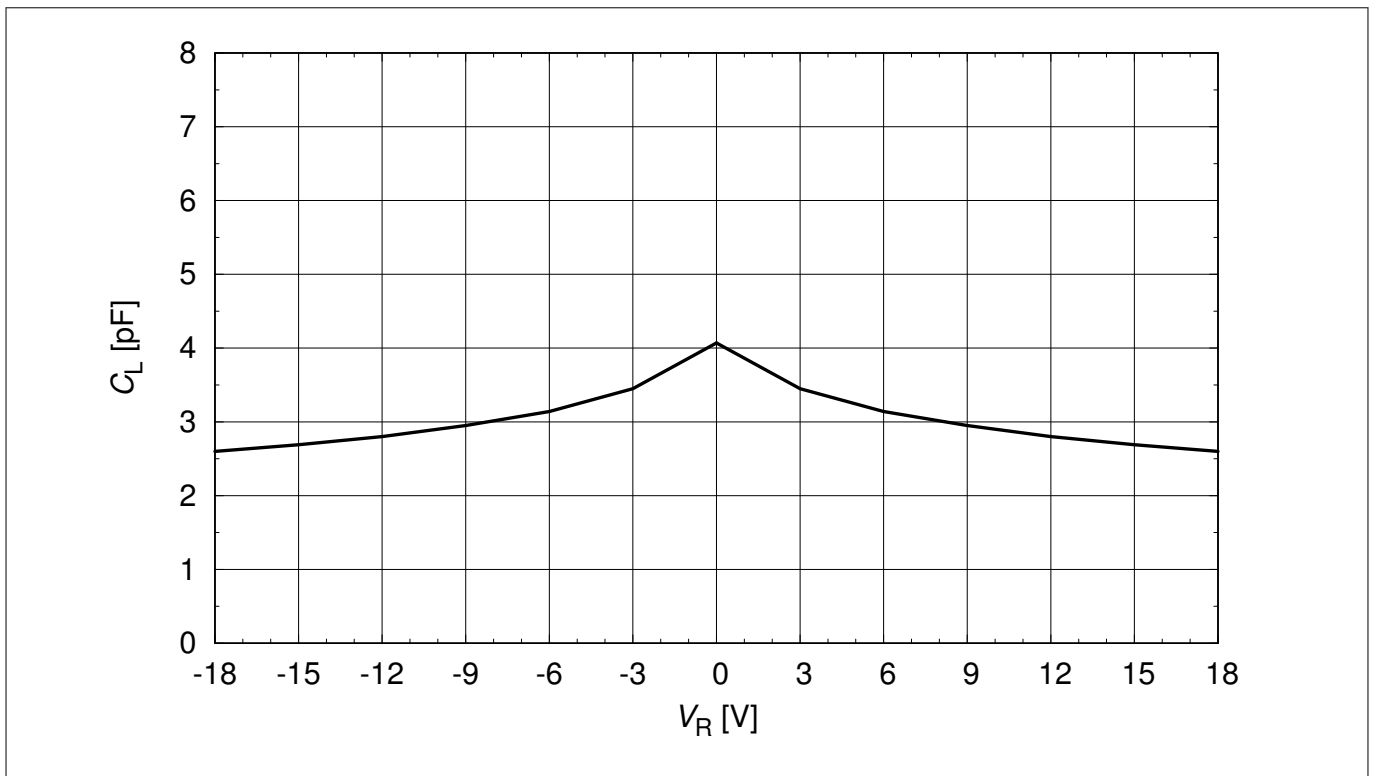


Figure 4 Line capacitance:  $C_L = f(V_R)$ ,  $f = 1\text{ MHz}$

Typical characteristic diagrams

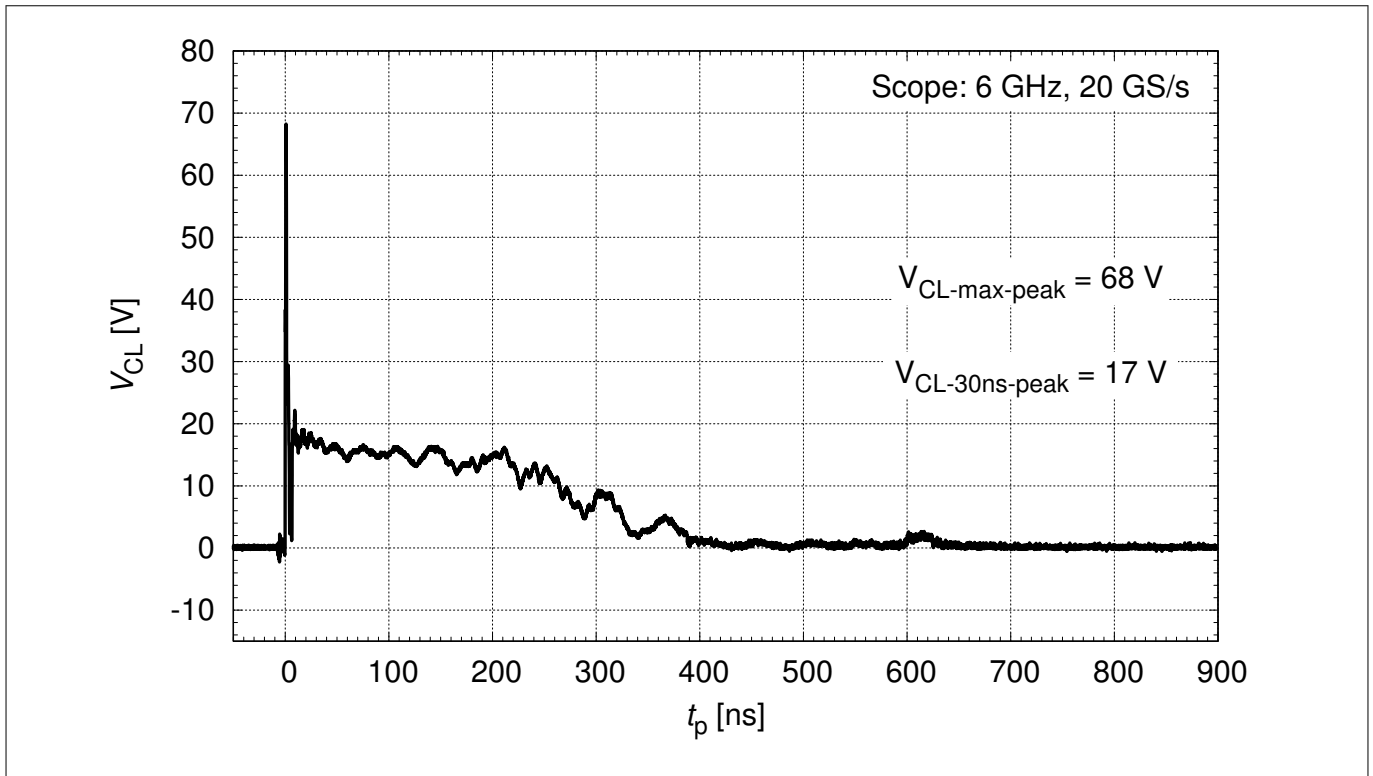


Figure 5 Clamping voltage (ESD):  $V_{CL} = f(t)$ , 8 kV positive pulse according to IEC61000-4-2

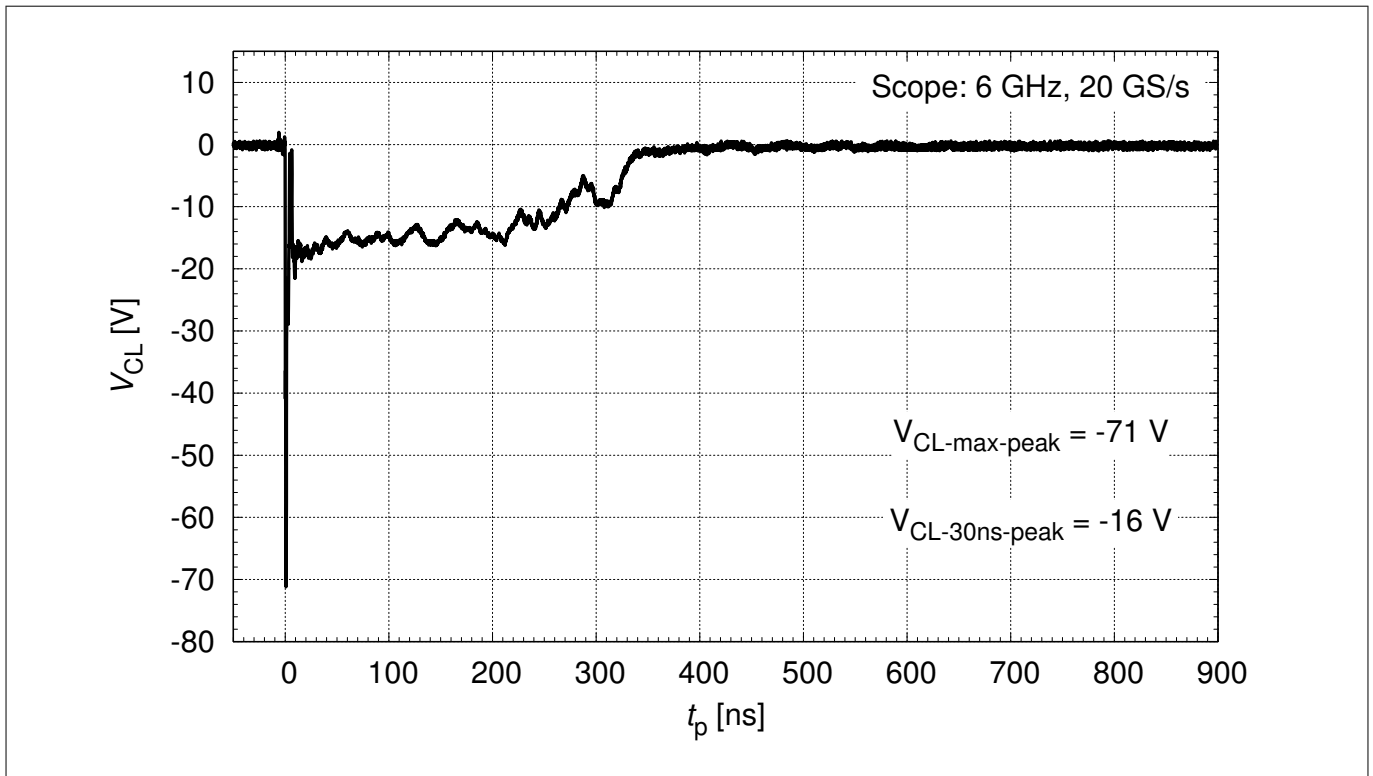


Figure 6 Clamping voltage (ESD):  $V_{CL} = f(t)$ , 8 kV negative pulse according to IEC61000-4-2

Typical characteristic diagrams

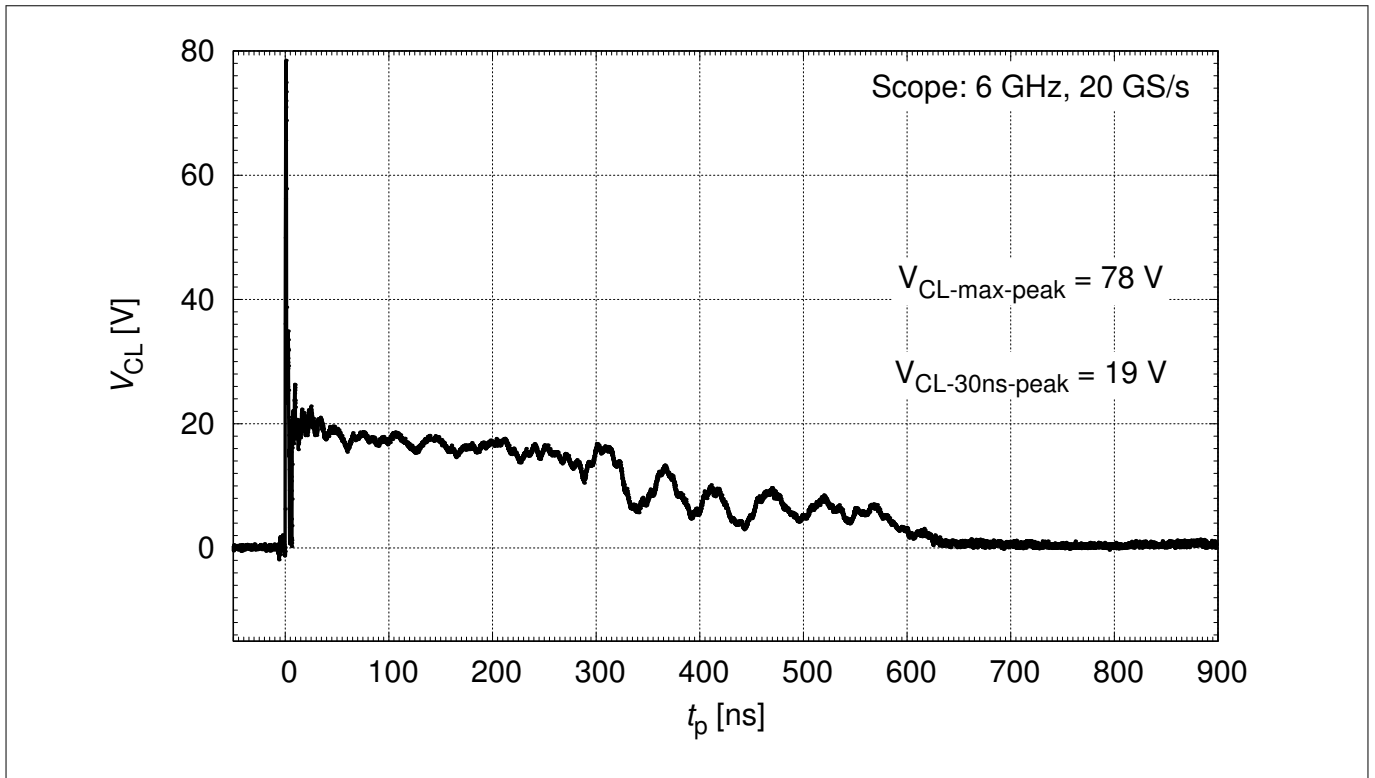


Figure 7 Clamping voltage (ESD):  $V_{CL} = f(t)$ , 15 kV positive pulse according to IEC61000-4-2

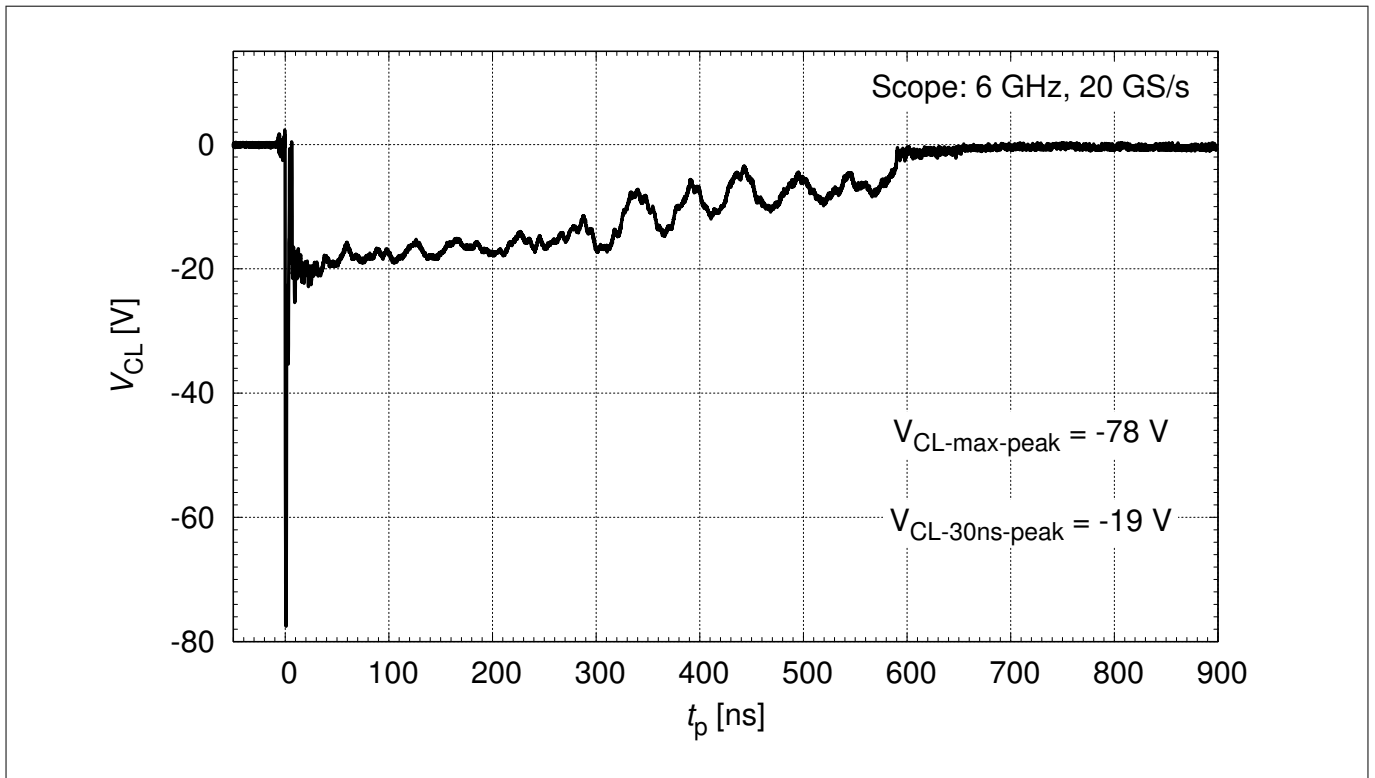
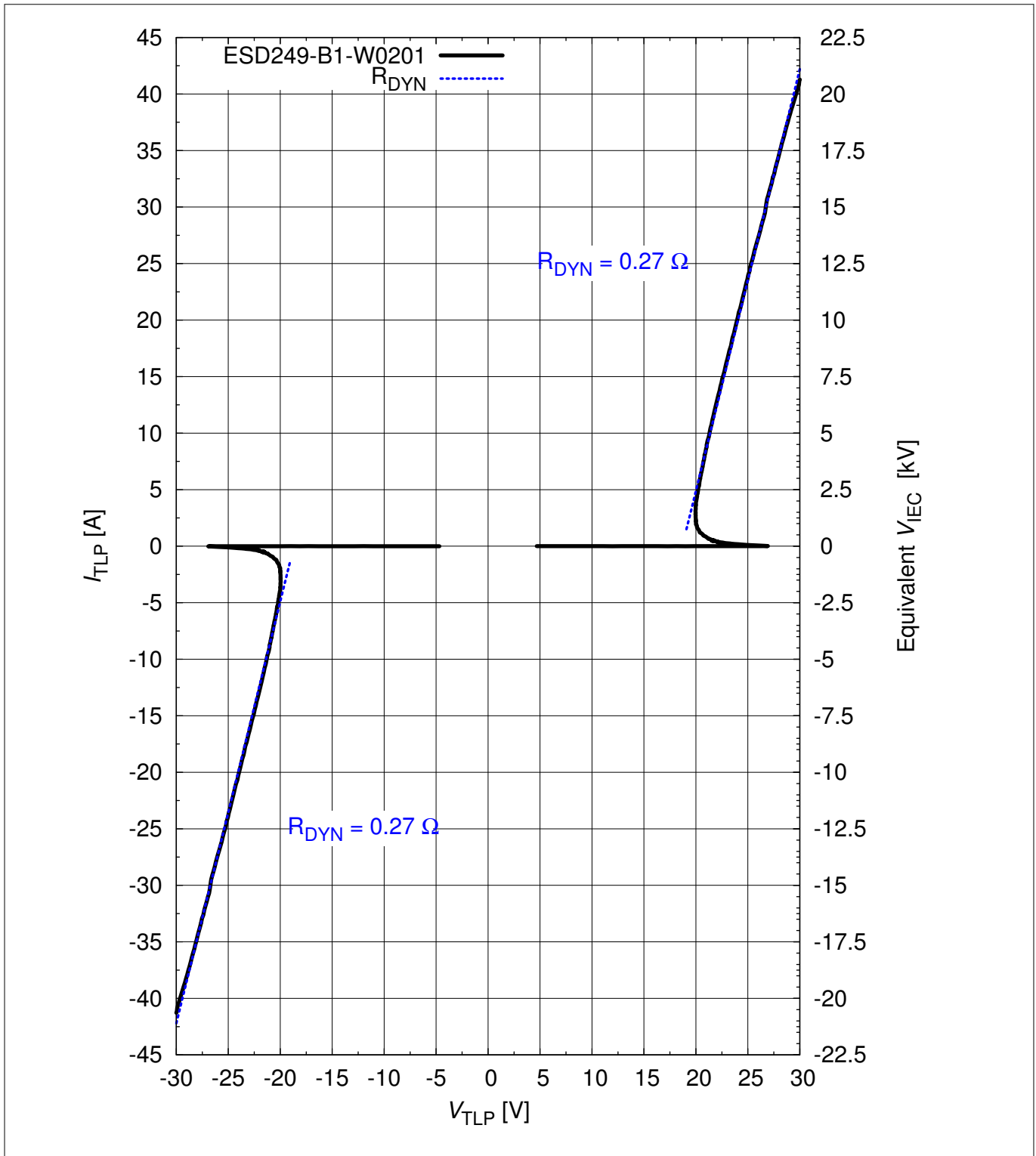


Figure 8 Clamping voltage (ESD):  $V_{CL} = f(t)$ , 15 kV negative pulse according to IEC61000-4-2



**Typical characteristic diagrams**



**Figure 9 Clamping voltage (TLP):  $I_{TLP} = f(V_{TLP})$  [1]**

Typical characteristic diagrams

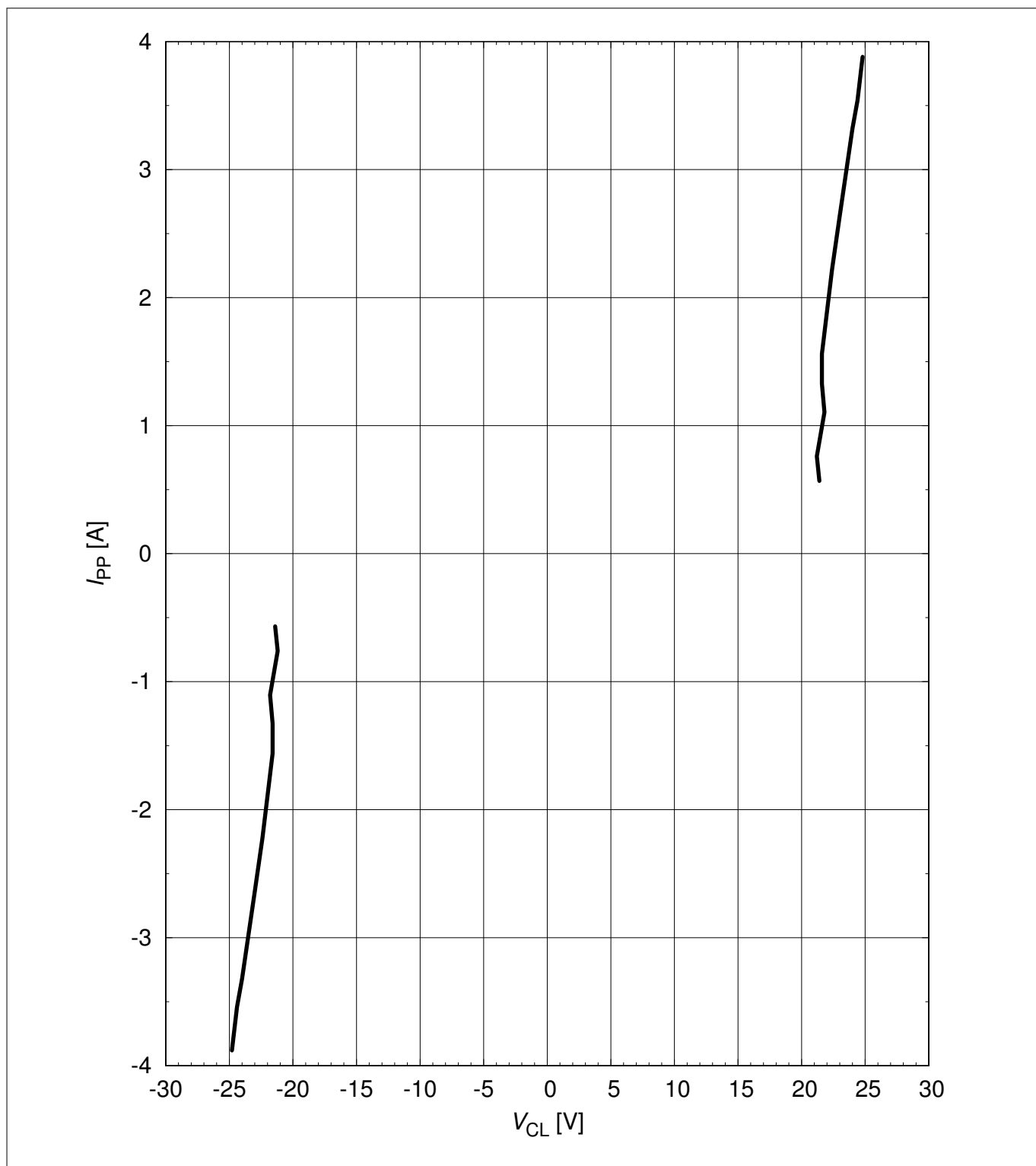


Figure 10 Clamping voltage (Surge):  $I_{PP} = f(V_{CL})$  according to IEC61000-4-5 [1]

Typical characteristic diagrams

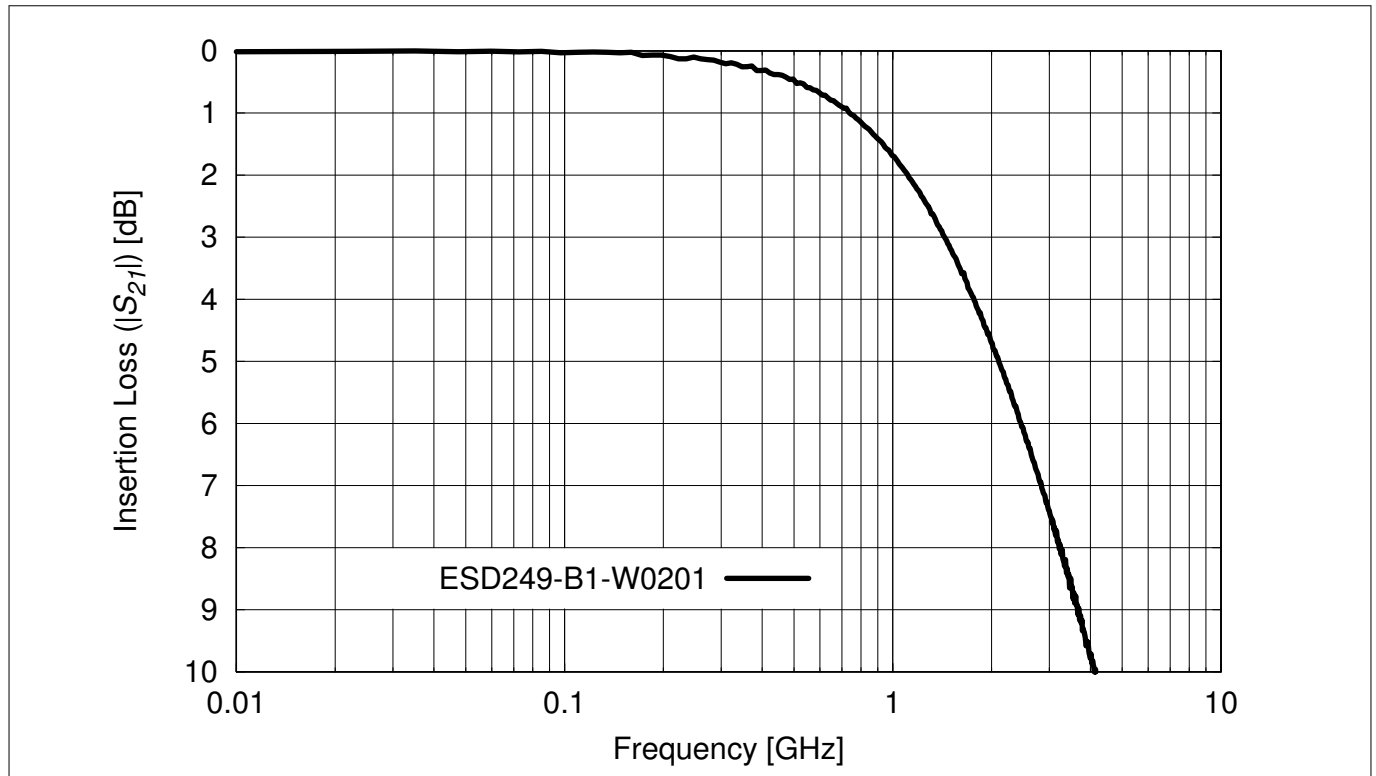


Figure 11 Insertion loss vs. frequency in a 50 Ω system

Package information

## 4 Package information

### 4.1 WLL-2-3 package

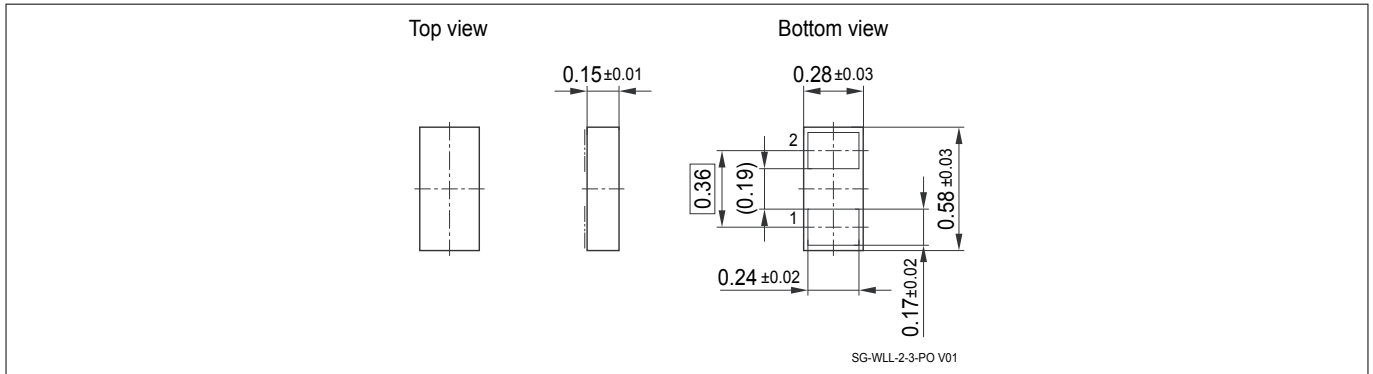


Figure 12 WLL-2-3 package outline (dimension in mm)

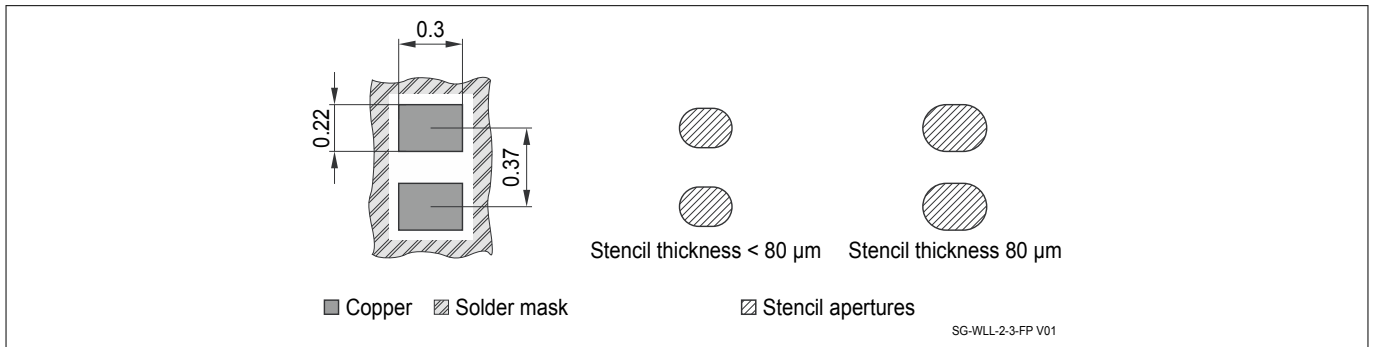


Figure 13 WLL-2-3 footprint (dimension in mm), recommendation for Printed Circuit Board Assembly see [2]

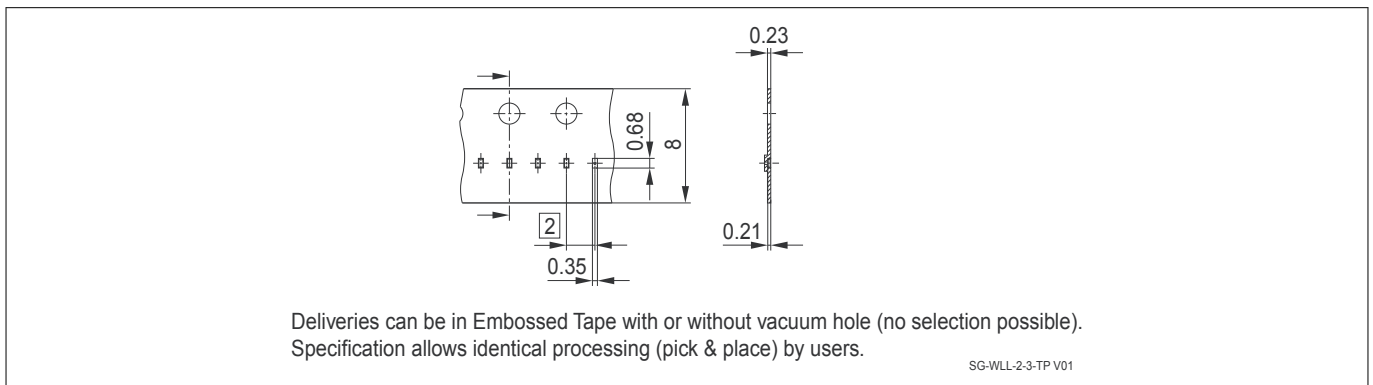


Figure 14 WLL-2-3 packing (dimension in mm)

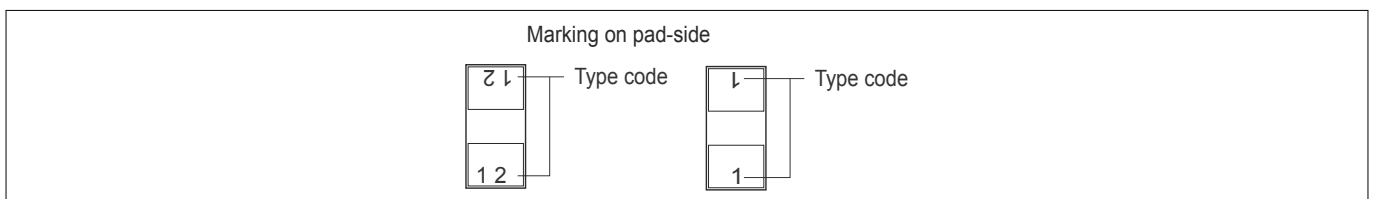


Figure 15 WLL-2-3 marking example (see Table 1)

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References

## 5 References

- [1] Infineon AG - **Application Note AN210**: Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology
- [2] Infineon AG - Recommendation for Printed Circuit Board Assembly of Infineon WLL Packages  
[http://www.infineon.com/Packageinformation\\_WLL](http://www.infineon.com/Packageinformation_WLL)
- [3] Infineon AG - **Application Note AN392**: TVS Diodes in ChipScalePackage reduce size and save cost

## Revision history

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**Revision history: Rev. 2017-02-24**

Page or Item	Subjects (major changes since previous revision)
Revision 1.1, 2017-03-14	
Table 3, 5	$V_{t1}$ , $V_h$ and $V_{CL}$ parameters updated

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